NSN 5962-01-375-3748

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View Online at https://aerobasegroup.com/nsn/5962-01-375-3748

Body Length: 0.480 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and hermetically sealed and monolithic and bipolar and schottky **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Current Rating Per Characteristic:** 140.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Ac0.840 Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, high to low level output and 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Prom **Test Data Document:**

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 printed circuit

Specification Data:

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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